TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74VHCT574AF, TC74VHCT574AFT, TC74VHCT574AFK

### Octal D-Type Flip-Flop with 3-State Output

The TC74VHCT574A is an advanced high speed CMOS OCTAL FLIP-FLOP with 3-STATE OUTPUT fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This 8-bit D-type flip-flop is controlled by a clock input (CK) and an output enable input  $(\overline{OE})$ .

When the  $\overline{OE}$  input is high, the eight outputs are in a high impedance state.

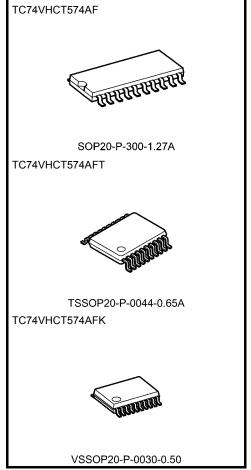
The input voltage are compatible with TTL output voltage. This device may be used as a level converter for interfacing  $3.3\ V$  to  $5\ V$  system.

Input protection and output circuit ensure that 0 to 5.5~V can be applied to the input and output  $^{\rm (Note)}$  pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

Note: Output in off-state

#### **Features**

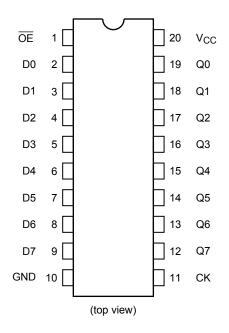
- High speed:  $f_{max} = 140 \text{ MHz}$  (typ.) at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 4 \mu A \text{ (max)}$  at  $T_{a} = 25 \text{°C}$
- Oompatible with TTL inputs:  $V_{IL} = 0.8 \ V \ (max)$   $V_{IH} = 2.0 \ V \ (min)$
- Power down protection is provided on all inputs and outputs.
- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Low noise: VOLP = 1.5 V (max)
- Pin and function compatible with the 74 series (74AC/HC/F/ALS/LS etc.) 574 type.



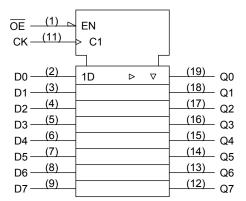
Weight

SOP20-P-300-1.27A: 0.22 g (typ.) TSSOP20-P-0044-0.65A: 0.08 g (typ.) VSSOP20-P-0030-0.50: 0.03 g (typ.)

### **Pin Assignment**



# **IEC Logic Symbol**



# **Truth Table**

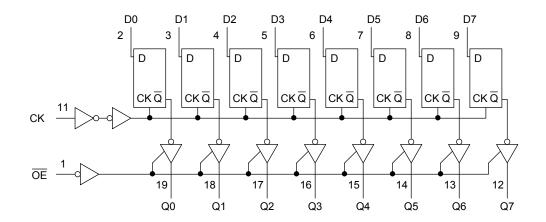
|    | Inputs | Output |        |
|----|--------|--------|--------|
| ŌĒ | CK     | D      | Output |
| Н  | Х      | Х      | Z      |
| L  | $\neg$ | Х      | Qn     |
| L  |        | L      | L      |
| L  |        | Н      | Н      |

X: Don't care

Z: High impedance

Qn: No change

### **System Diagram**





### **Absolute Maximum Ratings (Note 1)**

| Characteristics                    | Symbol           | Rating                                 | Unit |
|------------------------------------|------------------|----------------------------------------|------|
| Supply voltage range               | $V_{CC}$         | -0.5 to 7.0                            | V    |
| DC input voltage                   | V <sub>IN</sub>  | -0.5 to 7.0                            | V    |
| DC output voltage                  | Vour             | -0.5 to 7.0 (Note 2)                   | V    |
| DC output voltage                  | Vout             | -0.5 to V <sub>CC</sub> + 0.5 (Note 3) | V    |
| Input diode current                | I <sub>IK</sub>  | -20                                    | mA   |
| Output diode current               | lok              | ±20 (Note 4)                           | mA   |
| DC output current                  | Гоит             | ±25                                    | mA   |
| DC V <sub>CC</sub> /ground current | Icc              | ±75                                    | mA   |
| Power dissipation                  | P <sub>D</sub>   | 180                                    | mW   |
| Storage temperature                | T <sub>stg</sub> | -65 to 150                             | °C   |

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in off-state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: V<sub>OUT</sub> < GND, V<sub>OUT</sub> > V<sub>CC</sub>

### **Operating Ranges (Note 1)**

| Characteristics          | Symbol           | Rating                        | Unit |
|--------------------------|------------------|-------------------------------|------|
| Supply voltage           | V <sub>CC</sub>  | 4.5 to 5.5                    | V    |
| Input voltage            | V <sub>IN</sub>  | 0 to 5.5                      | V    |
| Output voltage           | V <sub>OUT</sub> | 0 to 5.5 (Note 2)             | V    |
| Output voltage           | ٧٥٥١             | 0 to V <sub>CC</sub> (Note 3) | V    |
| Operating temperature    | T <sub>opr</sub> | −40 to 85                     | °C   |
| Input rise and fall time | dt/dV            | 0 to 20                       | ns/V |

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V<sub>CC</sub> or GND.

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Note 2:  $V_{CC} = 0 V$ 

Note 3: High or low state



### **Electrical Characteristics**

### **DC Characteristics**

| Characteristics                  | Symbol           | Test Condition                                                                                    |                          | Ta = 25°C  |      |      | Ta =<br>-40 to 85°C |      | Unit  |    |
|----------------------------------|------------------|---------------------------------------------------------------------------------------------------|--------------------------|------------|------|------|---------------------|------|-------|----|
|                                  | 5,               |                                                                                                   |                          |            | Min  | Тур. | Max                 | Min  | Max   |    |
| High-level input voltage         | V <sub>IH</sub>  |                                                                                                   | -                        |            | 2.0  | _    | _                   | 2.0  | _     | V  |
| Low-level input voltage          | V <sub>IL</sub>  |                                                                                                   | _                        | 4.5 to 5.5 | _    | -    | 0.8                 | -    | 0.8   | V  |
| High-level output                | V <sub>OH</sub>  | V <sub>IN</sub>                                                                                   | I <sub>OH</sub> = -50 μA | 4.5        | 4.40 | 4.50 | _                   | 4.40 | _     | V  |
| voltage                          | VOH              | = V <sub>IH</sub> or V <sub>IL</sub>                                                              | I <sub>OH</sub> = -8 mA  | 4.5        | 3.94 | _    | _                   | 3.80 | _     |    |
| Low-level output                 | V <sub>OL</sub>  | V <sub>IN</sub>                                                                                   | I <sub>OL</sub> = 50 μA  | 4.5        | _    | 0.0  | 0.10                | _    | 0.10  | ٧  |
| voltage                          | VOL              | = V <sub>IH</sub> or V <sub>IL</sub>                                                              | I <sub>OL</sub> = 8 mA   | 4.5        | 1    | _    | 0.36                | 1    | 0.44  |    |
| 3-state output off-state current | I <sub>OZ</sub>  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub><br>V <sub>OUT</sub> = V <sub>CC</sub> or GND |                          | 5.5        |      | -    | ±0.25               |      | ±2.50 | μΑ |
| Input leakage<br>current         | I <sub>IN</sub>  | V <sub>IN</sub> = 5.5 V or GND                                                                    |                          | 0 to 5.5   | _    | _    | ±0.1                | _    | ±1.0  | μΑ |
|                                  | Icc              | V <sub>IN</sub> = V <sub>CC</sub> or GND                                                          |                          | 5.5        | _    | _    | 4.0                 | _    | 40.0  | μΑ |
| Quiescent supply current         | Ісст             | Per input: V <sub>IN</sub> = 3.4 V<br>Other input: V <sub>CC</sub> or GND                         |                          | 5.5        |      | -    | 1.35                | -    | 1.50  | mA |
| Output leakage current           | I <sub>OPD</sub> | V <sub>OUT</sub> = 5.5 \                                                                          | V <sub>OUT</sub> = 5.5 V |            | _    | _    | +0.5                | _    | +5.0  | μΑ |

# Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$ )

| Characteristics          | Symbol             | Test Condition |                     | Ta = | 25°C  | Ta =<br>-40 to 85°C | Unit |  |
|--------------------------|--------------------|----------------|---------------------|------|-------|---------------------|------|--|
| Ondracteristics Oymbor   |                    |                | V <sub>CC</sub> (V) | Тур. | Limit | Limit               | 2    |  |
| Minimum pulse width (CK) | t <sub>w (H)</sub> | _              | 5.0 ± 0.5           | _    | 6.5   | 8.5                 | ns   |  |
| Minimum set-up time      | t <sub>s</sub>     | _              | 5.0 ± 0.5           | _    | 2.5   | 2.5                 | ns   |  |
| Minimum hold time        | t <sub>h</sub>     | _              | 5.0 ± 0.5           | _    | 2.5   | 2.5                 | ns   |  |



### AC Characteristics (input: $t_r = t_f = 3$ ns)

| Characteristics               | Symbol            |                       | Test Condition      |                     | Ta = 25°C |      |      | Ta =<br>-40 to 85°C |      | Unit  |
|-------------------------------|-------------------|-----------------------|---------------------|---------------------|-----------|------|------|---------------------|------|-------|
|                               | ,                 |                       | V <sub>CC</sub> (V) | C <sub>L</sub> (pF) | Min       | Тур. | Max  | Min                 | Max  |       |
| Propagation delay time        | t <sub>pLH</sub>  | _                     | 5.0 ± 0.5           | 15                  | _         | 4.1  | 9.4  | 1.0                 | 10.5 | ns    |
| (CK-Q)                        | $t_{pHL}$         |                       | 0.0 _ 0.0           | 50                  | _         | 5.6  | 10.4 | 1.0                 | 11.5 | 113   |
| 3-state output enable         | $t_{pZL}$         | D. = 1 kO             | 50+05               | 15                  | _         | 6.5  | 10.2 | 1.0                 | 11.5 | ns    |
| time                          | t <sub>pZH</sub>  | $R_L = 1 k\Omega$     | 5.0 ± 0.5           | 50                  | _         | 7.3  | 11.2 | 1.0                 | 12.5 | 115   |
| 3-state output disable time   | t <sub>pLZ</sub>  | R <sub>L</sub> = 1 kΩ | 5.0 ± 0.5           | 50                  | _         | 7.0  | 11.2 | 1.0                 | 12.0 | ns    |
| Maximum clock                 | f <sub>max</sub>  | _                     | 5.0 ± 0.5           | 15                  | 90        | 140  | _    | 80                  | _    | MHz   |
| frequency                     |                   |                       |                     | 50                  | 85        | 130  | _    | 75                  | _    | IVITZ |
| Output to output skew         | t <sub>osLH</sub> | (Note 1)              | 5.0 ± 0.5           | 50                  | _         | _    | 1.0  | _                   | 1.0  | ns    |
| Input capacitance             | C <sub>IN</sub>   |                       | _                   |                     | _         | 4    | 10   | _                   | 10   | pF    |
| Output capacitance            | C <sub>OUT</sub>  |                       | _                   |                     | _         | 9    | _    | _                   | _    | pF    |
| Power dissipation capacitance | C <sub>PD</sub>   |                       |                     | (Note 2)            | _         | 25   | _    | _                   | _    | pF    |

Note 1: Parameter guaranteed by design.

$$t_{OSLH} = |t_{DLHm} - t_{DLHn}|, t_{OSHL} = |t_{DHLm} - t_{DHLn}|$$

Note 2: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 8 (per F/F)$$

And the total C<sub>PD</sub> when n pcs. of latch operate can be gained by the following equation:

C<sub>PD</sub> (total) = 14 + 11·n

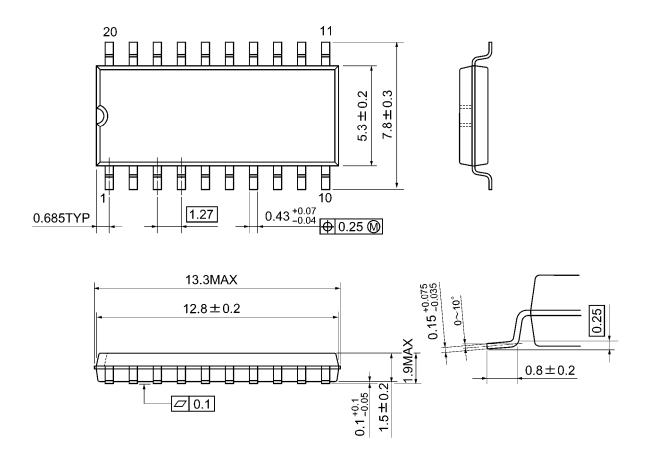
### Noise Characteristics (input: $t_r = t_f = 3$ ns)

| Characteristics                              | Symbol           | Test Condition         |                     | Ta = | Ta = 25°C |      |
|----------------------------------------------|------------------|------------------------|---------------------|------|-----------|------|
| Characteristics                              | Symbol           |                        | V <sub>CC</sub> (V) | Тур. | Limit     | Unit |
| Quiet output maximum dynamic V <sub>OL</sub> | $V_{OLP}$        | C <sub>L</sub> = 50 pF | 5.0                 | 1.1  | 1.5       | V    |
| Quiet output minimum dynamic V <sub>OL</sub> | V <sub>OLV</sub> | C <sub>L</sub> = 50 pF | 5.0                 | -1.1 | -1.5      | V    |
| Minimum high level dynamic input voltage     | $V_{IHD}$        | C <sub>L</sub> = 50 pF | 5.0                 | _    | 2.0       | V    |
| Maximum low level dynamic input voltage      | V <sub>ILD</sub> | C <sub>L</sub> = 50 pF | 5.0                 | _    | 0.8       | V    |

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# **Package Dimensions**

SOP20-P-300-1.27A Unit: mm

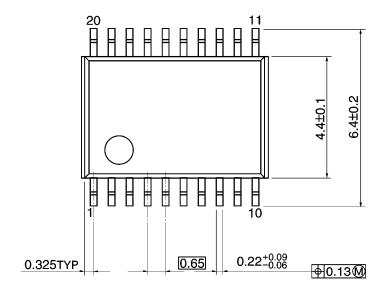


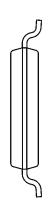
Weight: 0.22 g (typ.)

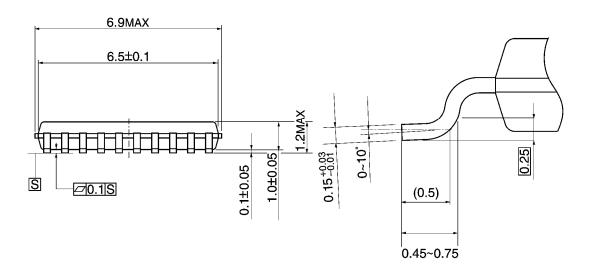
# **Package Dimensions**

TSSOP20-P-0044-0.65A

Unit: mm



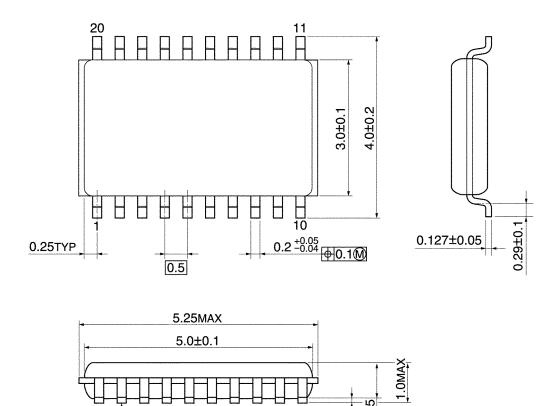




Weight: 0.08 g (typ.)

# **Package Dimensions**

VSSOP20-P-0030-0.50 Unit: mm



8

0.1±0.05

Weight: 0.03 g (typ.)

**270.1** 

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